



DUAL FET BUS SWITCH 2.5V OR 3.3V LOW-VOLTAGE HIGH-BANDWIDTH BUS SWITCH

■ DESCRIPTION

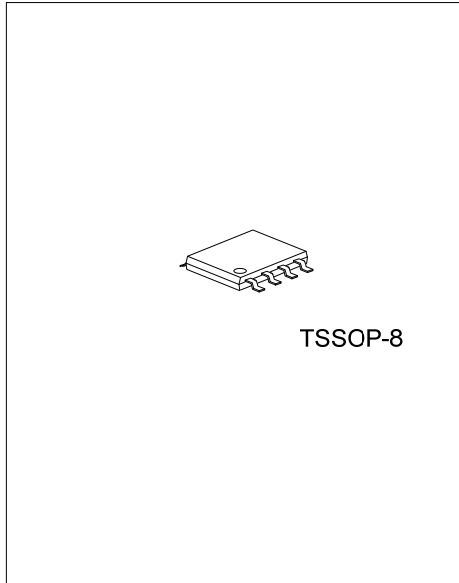
The **U74CB3Q3305** device is a high-bandwidth FET bus switch using a charge pump to elevate the gate voltage of the pass transistor, providing a low and flat ON-state resistance (R_{ON}). The low and flat ON-state resistance allows for minimal propagation delay and supports switching input voltage beyond the supply on the data input/output (I/O) ports. The device also features low data I/O capacitance to minimize capacitive loading and signal distortion on the data bus. Specifically designed to support high-bandwidth applications, the **U74CB3Q3305** device provides an optimized interface solution ideally suited for broadband communications, networking, and data-intensive computing systems.

This device is fully specified for partial-power-down applications using I_{OFF} . The I_{OFF} circuitry prevents damaging current backflow through the device when it is powered down. The device has isolation during power off

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

■ FEATURES

- * Operation Voltage Range: 2.3 ~ 3.6V
- * Low power consumption, 0.25mA Typ. I_{CC}
- * High-bandwidth data path (up to 500 MHz)
- * 5V tolerant I/Os with device powered up or powered down
- * Low and flat ON-state resistance (r_{on}) characteristics over operating range ($R_{on} = 3.5\Omega$ typical)
- * Supports input voltage beyond supply on data I/O ports
 - 0 to 5V switching with 3.3V V_{CC}
 - 0 to 3.3V switching with 2.5V V_{CC}
- * Data I/Os support 0 to 5 V signaling levels (0.8V, 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5V)
- * Control inputs can be driven by TTL or 5V/3.3V CMOS outputs
- * I_{OFF} supports partial-power-down mode operation

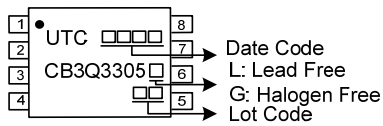


■ ORDERING INFORMATION

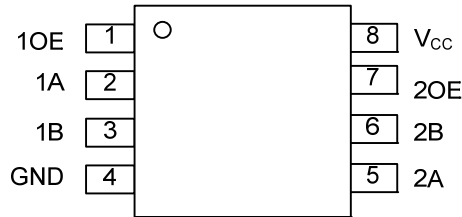
Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74CB3Q3305L-P08-R	U74CB3Q3305G-P08-R	TSSOP-8	Tape Reel

<p>U74CB3Q3305G-P08-R</p> <p>(1) Packing Type (2) Package Type (3) Green Package</p>	<p>(1) R: Tape Reel (2) P08: TSSOP-8 (3) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ MARKING



■ PIN CONFIGURATION



■ PIN CONFIGURATION

PIN No	SYMBOL	TYPE	DESCRIPTION
1	1OE	I	Output Enable for Switch 1
2	1A	I/O	Channel 1A Port
3	1B	I/O	Channel 1B Port
4	GND	P	Ground
5	2A	I/O	Channel 2A Port
6	2B	I/O	Channel 2B Port
7	2OE	I	Output Enable for Switch 2
8	V _{cc}	P	Power Supply

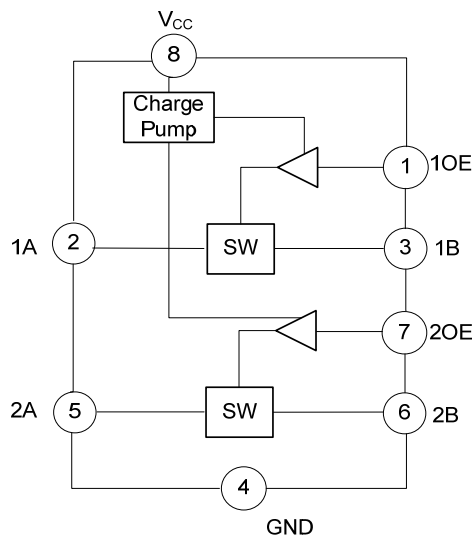
Note: I=Input, O=Output, I/O=Input and Output, P=Power.

■ FUNCTION TABLE (Each Bus Switch)

INPUT(\overline{OE})	INPUT(A)	FUNCTION
H	B	A Port = B Port
L	Z	Disconnect

Note: H: HIGH Voltage Level; L: LOW Voltage Level; Z=High-Impedance OFF-State.

■ LOGIC DIAGRAM (Positive Logic)



■ ABSOLUTE MAXIMUM RATINGS

Over recommended operating free-air temperature range (Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	RATINGS	UNIT
Supply Voltage	V_{CC}		-0.5 ~ 4.6	V
Input Voltage	V_{IN}		-0.5 ~ 7	V
Switch I/O Voltage Range	$V_{I/O}$		-0.5 ~ 7	V
Input Clamp Current	I_{IK}	$V_{IN} < 0V$	-50	mA
I/O Port Clamp Current	$I_{I/OK}$	$V_{OUT} < 0V$	-50	mA
ON-State Switch Current	$I_{I/O}$		±64	mA
Continuous Current Through V_{CC} or GND			±100	mA
Junction Temperature	T_J		+150	°C
Storage Temperature Range	T_{STG}		-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. V_I and V_O are used to denote specific conditions for $V_{I/O}$.

3. I_I and I_O are used to denote specific conditions for $I_{I/O}$.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}	2.3		3.6	V
Switch I/O Voltage Range	$V_{I/O}$	0		5.5	V
Operating Temperature	T_A	-40		+125	°C

■ ELECTRICAL CHARACTERISTICS

Over recommended operating free-air temperature range (Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
High-Level Input Voltage	V_{IH}	$V_{CC}=2.3V\sim 2.7V$	1.7			V
		$V_{CC}=2.7V\sim 3.6V$	2.0			V
Low-Level Output Voltage	V_{IL}	$V_{CC}=2.3V\sim 2.7V$			0.7	V
		$V_{CC}=2.7V\sim 3.6V$			0.8	V
Clamp Diode Voltage	V_{IK}	$V_{CC}=3.6V, I_I=-18mA$			-1.8	V
Input Current	Control Inputs I_{IN}	$V_{CC}=3.6V, V_{OUT}=0\sim 5.5V$			±1	μA
Output OFF-state current (Note 3)	I_{OZ}	$V_{CC}=3.6V, V_{OUT}=0\sim 5.5V, V_{IN}=0$, Switch OFF, $V_{IN}=V_{CC}$ or GND			±1	μA
OFF-state output current	I_{OFF}	$V_{CC}=0, V_{OUT}=0\sim 5.5V, V_{IN}=0$			1	μA
Quiescent Supply Current	I_{CC}	$V_{CC}=3.6V, I_{I/O}=0$, Switch ON or OFF, $V_{IN}=V_{CC}$ or GND		0.25	0.7	mA
Additional Quiescent Supply Current Per Input Pin	Control Inputs ΔI_{CC} (Note 4)	$V_{CC}=3.6V$, One Input at 3V, Other Inputs at V_{CC} or GND			25	μA
	Per Control Input I_{CCD} (Note 5)	$V_{CC}=3.6V$, A and B Ports Open, Control Input Switching at 50% duty cycle		0.04	0.045	mA/MHz
Input Capacitance	Control Inputs C_{IN}	$V_{CC}=3.3V, V_{IN}=5.5V, 3.3V, 0$		2.5	3.5	pF
OFF Output Capacitance	$C_{I/O(OFF)}$	$V_{CC}=3.3V$, Switch OFF, $V_{IN}=V_{CC}$ or GND, $V_{I/O}=5.5V, 3.3V, 0$		3.5	5.0	pF

■ ELECTRICAL CHARACTERISTICS (Cont.)

Over recommended operating free-air temperature range (Unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
ON Output Capacitance	$C_{IO(ON)}$	$V_{CC}=3.3V$, Switch ON, $V_{IN}=V_{CC}$ or GND, $V_{IO}=5.5V, 3.3V, 0$		8.0	10.5	pF	
Static Drain-Source On-State Resistance (Note 6)	$R_{DS(ON)}$	$V_{CC}=3.3V$, TYP at $V_{CC}=2.5V$	$V_{IN}=0, I_O=30mA$		3.5	8.0	Ω
			$V_{IN}=1.7V, I_O=-15mA$		4	9.0	Ω
		$V_{CC}=3.0V$	$V_{IN}=0, I_O=30mA$		3.5	6.0	Ω
			$V_{IN}=2.4V, I_O=-15mA$		4	8.0	Ω

Notes: 1. V_{IN} and I_{IN} refer to control inputs. V_I , V_O , I_I , and I_O refer to data pins.

2. All typical values are at $V_{CC}=3.3V$ (unless otherwise noted), $T_A=25^\circ C$.

3. For I/O ports, the parameter IOZ includes the input leakage current.

4. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

5. This parameter specifies the dynamic power-supply current associated with the operating frequency of a single control input.

6. Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

■ DYNAMIC CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	$T_A=25^\circ C$			$T_A=-40^\circ C \sim +125^\circ C$			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
From Input (OE) to Output (A or B) (Note 1)	f_{OE}	$V_{CC}=2.5V \pm 0.2V$			10			10	MHz
		$V_{CC}=3.3V \pm 0.3V$			20			20	MHz
Propagation Delay Time, From Input (A or B) to Output (B or A) (Note 2)	t_{PD} (t_{PLH}/t_{PHL})	$C_L=30pF$ $V_{CC}=2.5V \pm 0.2V$			0.2			0.6	ns
		$C_L=50pF$ $V_{CC}=3.3V \pm 0.3V$			0.2			0.6	ns
Enable Delay Time, From Input (OE) to Output (A or B)	t_{en} (t_{PZL}/t_{PZH})	$V_{CC}=2.5V \pm 0.2V$	1		12	1		13	ns
		$V_{CC}=3.3V \pm 0.3V$	1		6.5	1		7.5	ns
Disable Delay Time, From Input (OE) to Output (A or B)	t_{dis} (t_{PLZ}/t_{PHZ})	$V_{CC}=2.5V \pm 0.2V$	1		6	1		7.5	ns
		$V_{CC}=3.3V \pm 0.3V$	1		5.5	1		7	ns

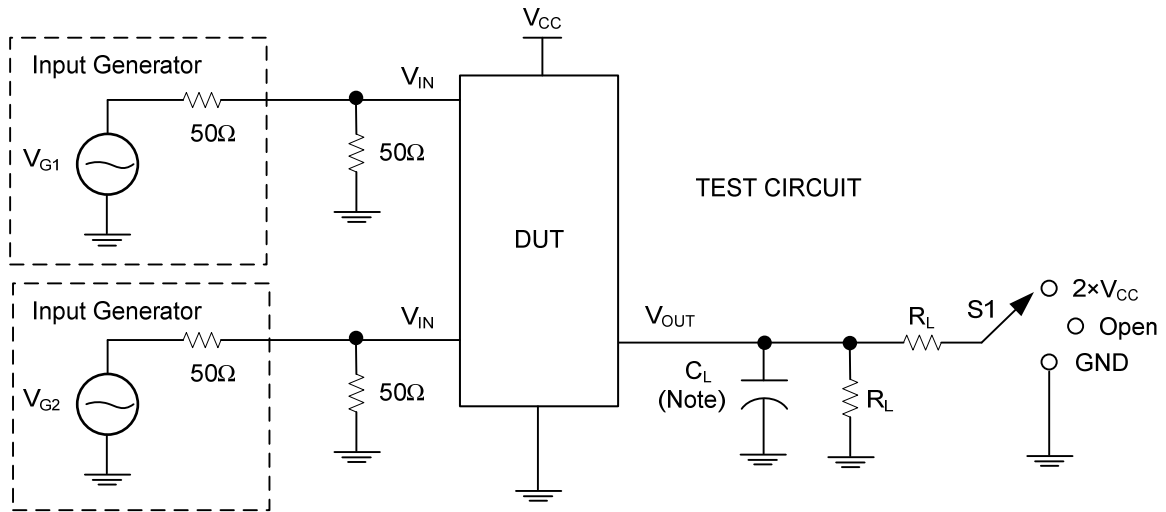
Notes: 1. Maximum switching frequency for control input ($V_O > V_{CC}$, $V_I = 5V$, $R_L \geq 1M\Omega$, $C_L = 0$).

2. The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

■ OPERATING CHARACTERISTIC

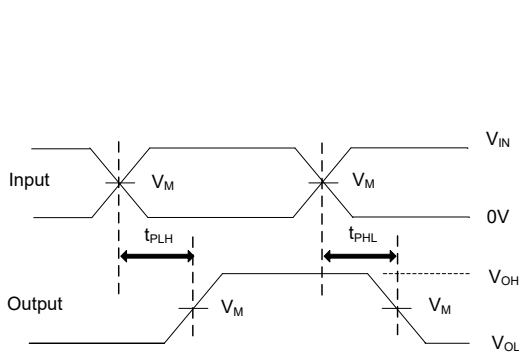
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C_{PD}	No load		32		pF

■ TEST CIRCUIT AND WAVEFORMS

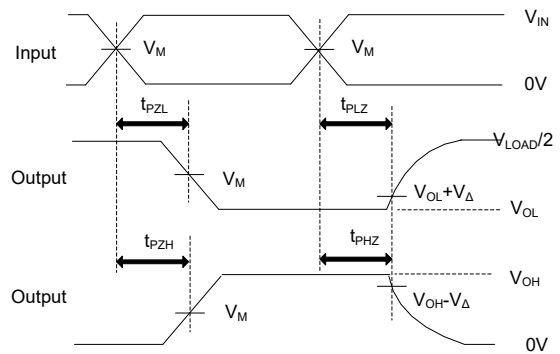


Note: C_L includes probe and jig capacitance.

TEST	V_{CC}	S1	R_L	V_{IN}	C_L	V_{Δ}
t_{PD} (t_{PLH}/t_{PHL})	$2.5V \pm 0.2V$	Open	500Ω	V_{CC} or GND	30pF	
	$3.3V \pm 0.3V$	Open	500Ω	V_{CC} or GND	50pF	
t_{en} (t_{PZL}/t_{PZH})	$2.5V \pm 0.2V$	$2 \times V_{CC}$	500Ω	GND	30pF	0.15V
	$3.3V \pm 0.3V$	$2 \times V_{CC}$	500Ω	GND	50pF	0.3V
t_{dis} (t_{PLZ}/t_{PHZ})	$2.5V \pm 0.2V$	GND	500Ω	V_{CC}	30pF	0.15V
	$3.3V \pm 0.3V$	GND	500Ω	V_{CC}	50pF	0.3V



PROPAGATION DELAY TIMES



ENABLE AND DISABLE TIMES

Notes: 1. C_L includes probe and test-fixture capacitance

2. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10MHz$, $Z_0 = 50\Omega$, $t_r < 2.5ns$, $t_f < 2.5ns$

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